

View Online at <https://aerobasegroup.com/nsn/5961-00-435-1800>

Inclosure Material:

Plastic all transistor

Overall Length:

0.240 inches all transistor

Terminal Length:

0.500 inches all transistor

Overall Diameter:

0.192 inches all transistor and 0.222 inches all transistor

Internal Configuration:

Junction contact all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Terminal Circle Diameter:

0.100 inches all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-base, emitter open all transistor and 25.0 breakdown voltage, collector-to-emitter, base open all transistor

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current all transistor and 5.00 nanoamperes zero-gate-voltage source current preset all transistor

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector absolute all transistor

Transfer Ratio:

10.0 static forward current transfer ratio, common-emitter all transistor

Maximum Operating Temperature Per Measurement Point:

125.0 degrees celsius junction all transistor

Terminal Type And Quantity:

3 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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